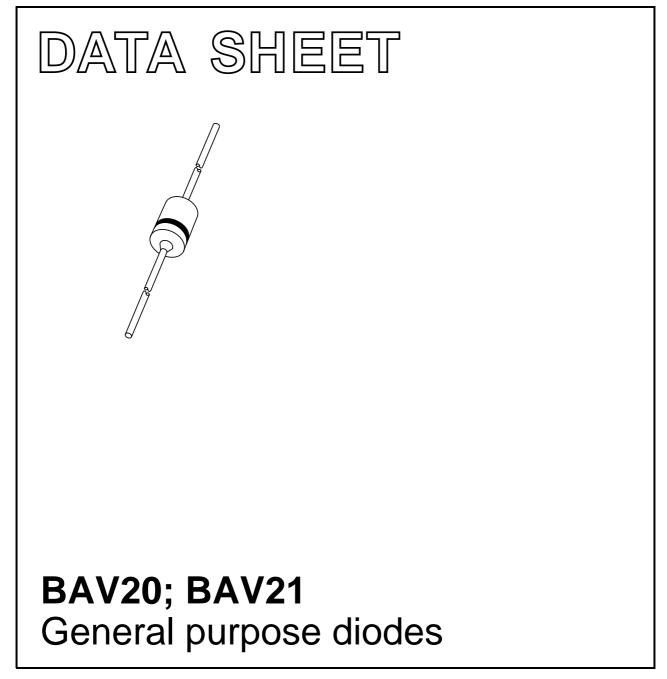
## DISCRETE SEMICONDUCTORS



Product data sheet Supersedes data of 1996 Sep 17 1999 May 25



### Product data sheet

### General purpose diodes

### **BAV20; BAV21**

### FEATURES

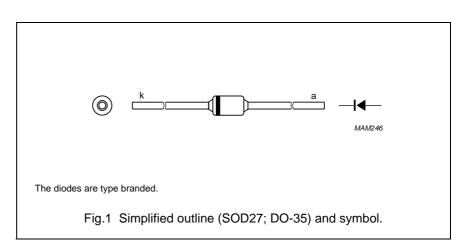
- Hermetically sealed leaded glass SOD27 (DO-35) package
- Switching speed: max. 50 ns
- General application
- Continuous reverse voltage: max. 150 V, 200 V
- Repetitive peak reverse voltage: max. 200 V, 250 V
- Repetitive peak forward current: max. 625 mA.

#### **APPLICATIONS**

 General purposes in industrial equipment e.g. oscilloscopes, digital voltmeters and video output stages in colour television.

#### DESCRIPTION

The BAV20 and BAV21 are switching diodes fabricated in planar technology, and encapsulated in hermetically sealed leaded glass SOD27 (DO-35) packages.



# BAV20; BAV21

### LIMITING VALUES

In accordance with the Absolute Maximum Rating System (IEC 134).

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
V <sub>RRM</sub>	repetitive peak reverse voltage				
	BAV20		-	200	V
	BAV21		_	250	V
V <sub>R</sub>	continuous peak reverse voltage				
	BAV20		_	150	V
	BAV21		_	200	V
l <sub>F</sub>	continuous forward current	see Fig.2; note 1	_	250	mA
I <sub>FRM</sub>	repetitive peak forward current		_	625	mA
I <sub>FSM</sub>	non-repetitive peak forward current	square wave; T <sub>j</sub> = 25 °C prior to surge; see Fig.4			
		t = 1 μs	_	9	А
		t = 100 μs	_	3	А
		t = 1 s	_	1	А
P <sub>tot</sub>	total power dissipation	T <sub>amb</sub> = 25 °C; note 1	-	400	mW
T <sub>stg</sub>	storage temperature		-65	+175	°C
Tj	junction temperature		_	175	°C

#### Note

1. Device mounted on an FR4 printed circuit-board; lead length 10 mm.

## BAV20; BAV21

### ELECTRICAL CHARACTERISTICS

 $T_j = 25 \ ^{\circ}C$  unless otherwise specified.

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
V <sub>F</sub>	forward voltage	see Fig.3			
		I <sub>F</sub> = 100 mA	-	1.0	V
		I <sub>F</sub> = 200 mA	-	1.25	V
I <sub>R</sub>	reverse current	see Fig.5			
		$V_{R} = V_{Rmax}$	-	100	nA
		V <sub>R</sub> = V <sub>Rmax</sub> ; T <sub>j</sub> = 150 °C	-	100	μΑ
C <sub>d</sub>	diode capacitance	$f = 1 MHz; V_R = 0; see Fig.6$	-	5	pF
t <sub>rr</sub>	reverse recovery time	when switched from $I_F = 30$ mA to $I_R = 30$ mA; $R_L = 100 \Omega$ ; measured at $I_R = 3$ mA; see Fig.8	_	50	ns

### THERMAL CHARACTERISTICS

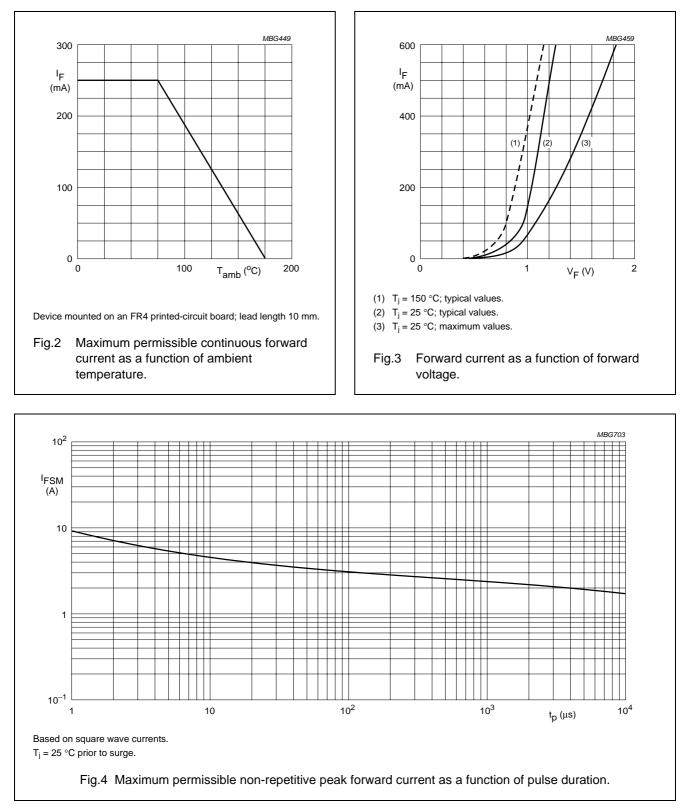
SYMBOL	PARAMETER	CONDITIONS	VALUE	UNIT
R <sub>th j-tp</sub>	thermal resistance from junction to tie-point	lead length 10 mm	240	K/W
R <sub>th j-a</sub>	thermal resistance from junction to ambient	lead length 10 mm; note 1	375	K/W

Note

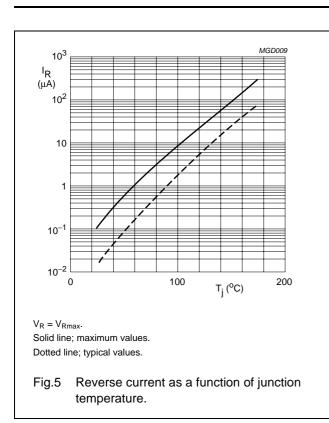
1. Device mounted on a printed circuit-board without metallization pad.

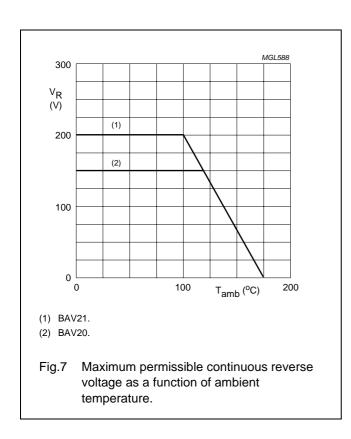
### BAV20; BAV21

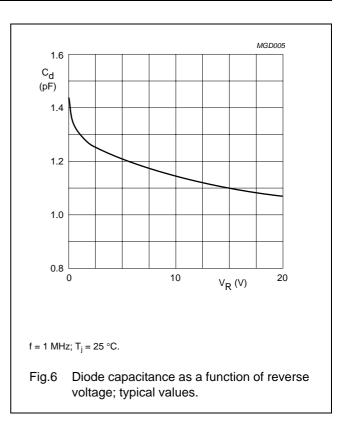
### **GRAPHICAL DATA**



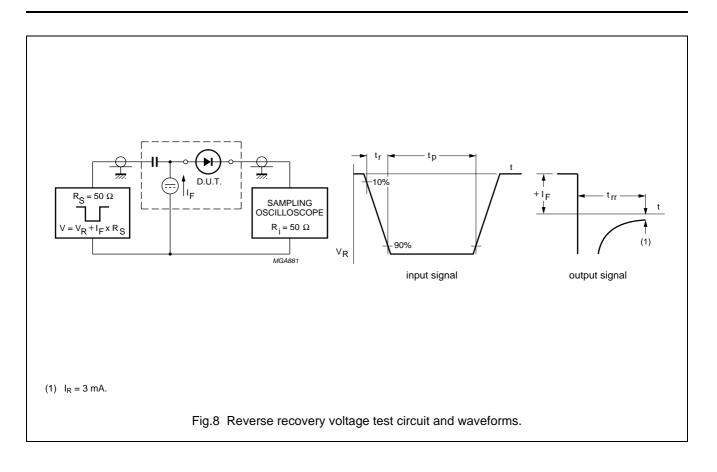
### BAV20; BAV21





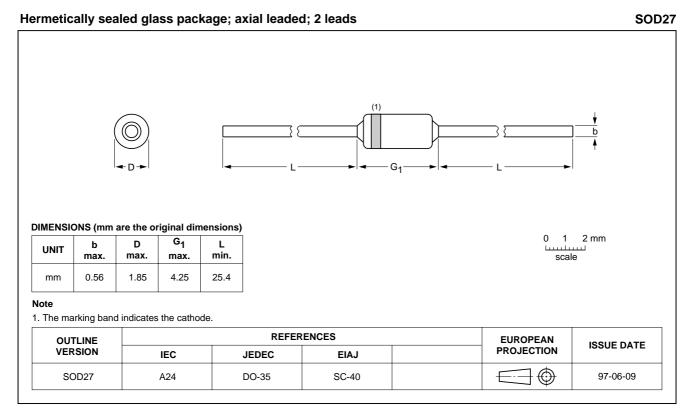


# BAV20; BAV21



### BAV20; BAV21

#### PACKAGE OUTLINE



### **BAV20; BAV21**

DOCUMENT STATUS <sup>(1)</sup>	PRODUCT STATUS <sup>(2)</sup>	DEFINITION
Objective data sheet	Development	This document contains data from the objective specification for product development.
Preliminary data sheet	Qualification	This document contains data from the preliminary specification.
Product data sheet	Production	This document contains the product specification.

#### Notes

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#### **Customer notification**

This data sheet was changed to reflect the new company name NXP Semiconductors. No changes were made to the content, except for the legal definitions and disclaimers.

#### **Contact information**

For additional information please visit: http://www.nxp.com For sales offices addresses send e-mail to: salesaddresses@nxp.com

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